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Noise measurement and modeling of a dual-frequency VECSEL at cesium clock wavelength

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Abstract— We study the noise of a class-A dual-frequency vertical external cavity surface emitting laser at Cesium clock wavelength. Both the intensity noise and phase noise of the beatnote between the two orthogonal polarized modes are measured and modeled. The intensity noise of the two orthogonal laser modes and its correlation are well predicted by a theory based on modified rate equations. The phase noise of the beatnote is predicted by the theory based on thermal effect and phase/amplitude coupling effect.

Keywords—Dual-frequency laser; vertical external cavity surface emitting laser; intensity noise; phase noise.

I. INTRODUCTION

The generation of optically carried radio frequency (RF) is an important issue in the area of microwave photonics (MWP), which has gained tremendous developments and has a bright future [1]. Dual-frequency vertical-external-cavity surface-emitting laser (DF-VECSEL) [2], sustaining two cross-polarized laser in a same optical cavity, is an attractive solution to generate such an optically carried RF signal. With class-A dynamics, DF-VECSEL can exhibit a low intensity noise and be free of relaxation oscillation (RO) [3], due to the fact that the lifetime of the photons inside the external cavity can be longer than the lifetime of the semiconductor gain media carriers. Additionally, DF-VECSEL is also interesting for atomic clocks. Indeed, coherent population trapping (CPT) atomic clock [4] is promising to realize miniaturized atomic clocks, but requires a trade-off between performance and size. Recently, a report gives out a solution using two pulses and a double lambda atomic system to obtain high contrast Ramsey fringes [5]. It is expected that the trade-off can be improved by the combination of DF-VECSEL and the double lambda atomic system configuration of CPT atomic clocks [6].

The study of noise of the DF-VECSEL is important and interesting, because it conveys information on the laser dynamics, enabling us to understand and control its behavior. DF-VECSEL was first experimentally demonstrated at 1 μm [2], showing the advantage of no RO, which is inherent to Class-B laser, for example, Nd:YAG [7]. Later, the DF-VECSEL at telecom wavelength (1.55 μm) [8] was reported

and its behavior in terms of spectra of intensity and phase noises was investigated in theory and experiment [9][10]. The experimental results were very well predicted by a theory based on modified rate equations. The validity of this theory has been even more solid after the success of the analysis of the correlation between the different noises [11]. Rich information about the laser can be revealed using this theory. Meanwhile, a DF-VECSEL specifically designed for Cesium CPT atomic clock was reported [6]. Since the modified rate equations successfully applied to the telecom wavelength DF-VECSEL, it is worth applying this theory to another DF-VECSEL with different wavelength to validate its generality.

This paper reports a DF-VECSEL wavelength at cesium clock. A special attention is paid in the measurement and modeling of the intensity noise and phase noise. The modeling is based on the modified rate equations.

II. CHARACTERISTICS OF THE DF-VECSEL

A. Configuration of the DF-VECSEL

Figure 1 is a schematics of the DF-VECSEL. The cavity is composed of a semiconductor chip the temperature of which is stabilized at 20 $^{\circ}\text{C}$ by a Peltier cooler and a heat sink, and a concave mirror with a 5 cm radius of curvature. The transmittivity of concave mirror is 0.5% at the laser wavelength (852 nm). A YVO₄ birefringent crystal with a thickness of 0.5mm, cut at 45 $^{\circ}$ to its optical axis anti-reflection coated, is inserted inside the cavity to create two optical paths, also introducing a spatial separation. The transverse separation between the two orthogonally separated laser modes, denoted as d , is about 50 μm . The etalon, with a thickness of 150 μm , is used for making each of the cross-polarized modes to emit in a single longitudinal mode. The length of the cavity is 48.0 mm, corresponding a laser mode with a waist of 50 μm on the semiconductor chip.

The semiconductor chip is composed of a Bragg mirror and an active structure. The Bragg mirror contains 32.5 pairs of half-wavelength AlAs/Al_{0.22}GaAs layers. The reflectivity of this Bragg mirror is very close to 100 %. The active layers contain seven quantum wells (8nm-GaAs) embedded in

$\text{Al}_{0.22}\text{GaAs}$ barriers, which absorb the pump laser, two layers of 30nm $\text{Al}_{0.39}\text{GaAs}$ used for the carrier confinement, and protective layers (50nm InGaP and 5nm GaAs) to prevent aluminum oxidation. All of the quantum wells are designed to be located at antinodes of the laser field. When a pump beam with spot diameter of 80 μm is incident on the chip with 40° incident angle, the reflected power is 25%, indicating that the absorption the pump power is about 75%. This chip is designed without anti-reflection coating to increase the gain of the mode resonant with the micro-cavity created in the semiconductor structure.

Fig. 1. The schematic of the DF-VECSEL

The pump laser, at a wavelength of 673nm, is a laser diode coupled to a multimode fiber with a 102 μm core diameter. The incident angle of the pump laser is 40°, leading to a 100 μm ×130 μm elliptical pump spot on the semiconductor chip. For this experiment, the pump power is set at 1.1 Watt.

B. Observation of two mode oscillation and beatnote

The two mode oscillation was monitored by observing the transmission signal of a Fabry - Perot interferometer (FPI), which is shown in Fig. 2(a). The beatnote was analyzed by a electric spectrum analyzer (ESA). Due to the 1 GHz limitation of response bandwidth of the photo-detector (PD) and 500 MHz bandwidth of the radio-frequency amplifier (RFA), the frequency of the beatnote was adjusted to be equal to 350 MHz. As shown in Fig.2(b), above the floor, a noise pedestal can be seen at the foot of the beatnote peak, with a few tens of MHz bandwidth, which will be discussed in the next section.

Fig. 2. (a) Optical spectrum of the DF-VECSEL analyzed by FPI. (b) Beatnote spectrum analyzed by ESA

III. NOISE MEASUREMENT AND MODELING

A. Pump noise measurement

Since both the intensity noise of the two orthogonally polarized modes and the phase noise of the beatnote mainly come from the pump noise, it is necessary to characterize this pump noise. The pump laser is multimode fiber coupled, so the modal noise exists in the pump beam due to the varying interference between the numerous spatial modes. The pump noise that eventually feeds the laser intensity and phase noises must be considered only in the regions of the semiconductor chip that amplify the two VECSEL laser modes. This fact

requires us to extract the pump noises just in the spatial regions that intersect the two VECSEL modes. Moreover, to measure the correlations between the pump regions that pump the two modes, we must record their noises simultaneously. To this aim, we built the experiment setup schematized in Fig. 3. The laser diode (LD) and the lens tube are the ones used to pump the DF-VECSEL. A beam splitter follows the lens tube to split the pump beam into two identical arms. At the focal point, two pinholes of 50 μm radii are placed to mimic the two laser modes. Each of the pinholes is controlled by a three dimension translation stage. We can thus record the two pump noises as a function of their separation d on the structure. After passing through the pinholes, the lens and the neutral density filters, the beams are sent to PDs with a photosensitive area of 2.4 mm×2.8 mm and a bandwidth of 30 MHz. The photocurrent signals are separated into DC and AC signals by a bias-tee. The AC signals are amplified by RFAs. The two signals are sampled by a digital oscilloscope simultaneously.

Fig. 4 shows the relative intensity noise (RIN) of the pump. RIN is defined as $RIN = \langle |\delta \tilde{P}(f)|^2 \rangle / P_0^2$, where $\delta \tilde{P}(f)$ is the Fourier Transform of the fluctuation of $P(t)$, $\langle \rangle$ denotes the ensemble average, P_0 is the average of $P(t)$. Here, P is the pump power. For simplicity, in subsequent modeling, we take the RIN of the pump to be white in the range from 10 kHz to 30 MHz, and take it equal to -130 dB/Hz.

Fig. 3. Experimental setup for pump noise measurement

Fig. 4. RIN spectrum of the pump laser

Fig. 5. (a) Amplitude and (b) phase of the correlation between the pump noise in two regions separated by distance d .

Fig. 5 shows the results of the correlations between the two pump noises selected by pinholes of 50 μm radius whose

images are separated by a distance d in the transverse plane. The measurement starts with $d = 0$, for which the correlation amplitude is almost equal to 1, illustrating the identity of the two pump regions passing through the pinholes. When d increase from 0 to 100 μm , the correlation amplitude decreases, and the correlation phase concentrates around zero. However, when d increase up to 125 μm and 150 μm , the correlation amplitude increase again, and the correlation phase tends to $\pm 180^\circ$.

B. Intensity noise measurement and modeling

The intensity and phase noises of the DF-VECSEL are measured by the experimental setup shown in Fig. 6. The beam emitted by the DF-VECSEL is split into two arms. In order to measure the intensity noise of the ordinary (o) and the extraordinary (e) modes separately, the orthogonal polarizations in one arm are separated by using a half wave plate and a PBS. The other arm, projecting the o and e modes into a same polarization direction, is used for the detection of the beatnote. Then, the three beams are sent into three PDs with a 1 GHz bandwidth. After amplification by RFAs, the intensity noise and beatnote are recorded by a deep memory digital oscilloscope.

Fig. 6. Schematic of the experimental setup for intensity and phase noise measurement.

The modeling is based on modified laser rate equations. According to this theory, the Fourier transforms of the intensity noises of the x - and y -polarized modes can be related in the frequency domain to the pump noises by a matrix [9], which is

$$\begin{bmatrix} \delta\tilde{F}_x(f) \\ \delta\tilde{F}_y(f) \end{bmatrix} = \begin{bmatrix} M_{xx}(f) & M_{xy}(f) \\ M_{yx}(f) & M_{yy}(f) \end{bmatrix} \begin{bmatrix} \delta\tilde{N}_{0x}(f) \\ \delta\tilde{N}_{0y}(f) \end{bmatrix} \quad (1)$$

with

$$M_{xx} = [1/\tau_y - 2i\pi f(r_y/\tau - 2i\pi f)/\kappa F_{y0}]/\Delta(f)\tau, \quad (2)$$

$$M_{yy} = [1/\tau_x - 2i\pi f(r_x/\tau - 2i\pi f)/\kappa F_{x0}]/\Delta(f)\tau, \quad (3)$$

$$M_{xy} = -\xi_{xy}/\tau\tau_x\Delta(f), \quad (4)$$

$$M_{yx} = -\xi_{yx}/\tau\tau_y\Delta(f), \quad (5)$$

where

$$\Delta(f) = \frac{[1/\tau_x - 2i\pi f(r_x/\tau - 2i\pi f)/\kappa F_{x0}]}{[1/\tau_y - 2i\pi f(r_y/\tau - 2i\pi f)/\kappa F_{y0}] - C/\tau_x\tau_y}. \quad (6)$$

In these equations, $\delta\tilde{F}_x$, $\delta\tilde{F}_y$ denote the Fourier transforms of fluctuations in photon numbers for the two modes inside the laser cavity. F_{x0} and F_{y0} are the average photon numbers. $\delta\tilde{N}_{0x}$ and $\delta\tilde{N}_{0y}$ denote the pump noise spectra for the two modes, τ is the population inversion lifetime, τ_x , τ_y are the photon lifetimes for the two modes, r_x , r_y denote their excitation ratios, ξ_{xy} , ξ_{yx} denote the cross- to self-saturation

coefficient ratios, $C = \xi_{xy}\xi_{yx}$, and κ is proportional to the stimulated emission cross section.

Fig. 7. The results of intensity noise measurement and modeling. Dotted lines denote the experimental results. (a) is the RIN of the intensity noise, (b) is the correlation amplitude, (c) is the correlation phase, (d) is the RIN of in-phase and anti-phase noise. The parameters used in the modeling are $\tau=1\text{ns}$, $\tau_x=15\text{ns}$, $\tau_y=19\text{ns}$, $r_x=1.53$, $r_y=1.59$, $\text{RIN}_{\text{pump}}=-132\text{dB/Hz}$, correlation amplitude $\eta=0.38$ and phase $\psi=0$, $C=0.38$.

Figure 7 shows the results of intensity noise measurement and modeling. Fig. 7 (a) is the RIN spectrum for the two modes. The shape of the RIN spectrum exhibits the typical first-order filter shape for class-A laser dynamics. Figures 7 (b) and 7 (c) are the amplitude and phase of the intensity noise correlation spectrum between the two modes. As can be seen, the correlation amplitude is flat and strong at the lower frequencies, before dropping and exhibiting a minimum in a narrow frequency band, after which it remains flat at a relatively low value. The corresponding correlation phase changes from about $\pm 180^\circ$ to 0° . This spectral behavior can be explained by considering the DF-VECSEL as a coupled oscillator system. Then, this system has two noise eigenmodes, i. e. in-phase mode (sum of the intensities of the two laser modes) and anti-phase mode (difference of the intensities of the two modes). As an approximation, supposing the two laser modes have the same gain and losses, the in-phase and anti-phase noise complex spectra are defined as $\delta\tilde{F}_{\text{In}} = \delta\tilde{F}_x + \delta\tilde{F}_y$, $\delta\tilde{F}_{\text{Anti}} = \delta\tilde{F}_x - \delta\tilde{F}_y$. The RIN spectra of the in-phase and anti-phase noises are shown in the Fig. 7 (d). One notices that the anti-phase noise is dominant over the in-phase noise at low frequencies, and conversely at higher frequencies. Since the correlation between $\delta\tilde{F}_x$ and $\delta\tilde{F}_y$ reads

$$\begin{aligned} \text{Cor}_{\delta\tilde{F}_x, \delta\tilde{F}_y} &= \frac{\langle \delta\tilde{F}_x \cdot \delta\tilde{F}_y^* \rangle}{\sqrt{\langle |\delta\tilde{F}_x|^2 \rangle} \cdot \sqrt{\langle |\delta\tilde{F}_y|^2 \rangle}} = \\ &= \frac{\langle |\delta\tilde{F}_{\text{In}}|^2 - |\delta\tilde{F}_{\text{Anti}}|^2 + (\delta\tilde{F}_{\text{Anti}} \cdot \delta\tilde{F}_{\text{In}}^* - \delta\tilde{F}_{\text{In}} \cdot \delta\tilde{F}_{\text{Anti}}^*) \rangle}{4\sqrt{\langle |\delta\tilde{F}_x|^2 \rangle} \cdot \sqrt{\langle |\delta\tilde{F}_y|^2 \rangle}} \\ &= \frac{\langle |\delta\tilde{F}_{\text{In}}|^2 - |\delta\tilde{F}_{\text{Anti}}|^2 \rangle}{4\sqrt{\langle |\delta\tilde{F}_x|^2 \rangle} \cdot \sqrt{\langle |\delta\tilde{F}_y|^2 \rangle}} \end{aligned} \quad (7)$$

the spectral behavior of the correlation between δF_x and δF_y can be readily explained. Since the difference between in-phase and anti-phase intensity noise is large at low frequency, the correlation amplitude is high. However, when the difference between the amplitudes of the two mechanisms becomes smaller, the correlation amplitude decreases. Besides, the correlation phase tends to be $\pm 180^\circ$ when the anti-phase noise is dominant, and 0° when the in-phase noise is dominant. At the crossing point of the in-phase and anti-phase noise mechanisms, a dip appears due to the lower correlation amplitude.

C. Phase noise of beatnote measurement and modeling

Figure 8 shows the phase noise measurement and modeling. The phase noise spectrum clearly exhibits a change of slope at around 300 kHz, showing that two mechanisms have to be considered, namely the one related to thermal effects and the one attributed to Henry's phase/amplitude coupling [10]. Considering the two effects, the phase noise can be expressed as [10]:

$$\delta\tilde{\phi}_{beat}(f) = \delta\tilde{\phi}_H(f) + \delta\tilde{\phi}_T(f) \quad (8)$$

$$\delta\tilde{\phi}_H(f) = \frac{\alpha}{2} \left(\frac{\delta\tilde{F}_x(f)}{F_{x0}} - \frac{\delta\tilde{F}_y(f)}{F_{y0}} \right) \quad (9)$$

$$\delta\tilde{\phi}_T(f) = \frac{\omega_0}{i2\pi f} \Gamma_T R_T \frac{1}{1 + i2\pi f \tau_T} P_p \left(\frac{\delta N_{0x}(f)}{N_{0x}} - \frac{\delta N_{0y}(f)}{N_{0y}} \right) \quad (10)$$

where α is Henry's factor, ω_0 is the frequency of laser, R_T is the thermal resistance, P_p is the pump power. Γ_T is defined as

$$\Gamma_T = (L_{sc} / L_{ext}) (dn / dT) \quad (11)$$

where L_{sc} and L_{ext} are the lengths of the semiconductor structure and the external cavity, respectively, dn / dT is the average thermal coefficient of the structure refractive index. τ_T is the thermal response time given by

$$\tau_T \approx w_p^2 / 2\pi D_T \quad (12)$$

Where w_p is the waist of pump beam and D_T is the thermal diffusion coefficient.

Based on these equations, the modeling is in very good agreement with the experimental result.

Fig. 8. Results of phase noise of the beatnote measurement and modeling. Dotted lines denote the experimental results. Parameters used in the modeling are $\alpha=3$, $\tau_T=1.4 \times 10^{-5}$ s, $R_T=6.7$ KW $^{-1}$, $\Gamma_T=3.87 \times 10^{-8}$ K $^{-1}$ $P_p=1.1$ W.

IV. CONCLUSIONS

In this paper, we have studied the noise mechanisms in a DF-VECSEL operating at the wavelength of Cesium clocks. We observed the beatnote sitting on a noise pedestal of a few tens of MHz bandwidth, and analyzed its origin. Firstly, the pump noise, including RIN and correlation between the two pump noises at different spatial locations, is measured in a dedicated setup. Since the pump noise is the major source of intensity noise and phase noise of the beatnote, this measurement allows us to model the laser noise accordingly. Secondly, the intensity noise was measured, including the RIN and the correlation between the noises of the two modes. The results was well predicted by a modified rate equation model. The behavior of the correlation spectra was explained by the existence and response of in-phase and anti-phase noise mechanisms. Finally, the phase noise of the beatnote was measured and modeled by considering the effect of phase/amplitude coupling in the quantum well and thermal effect of the semiconductor chip induced by the pump laser. The agreement between the experimental and theoretical results gives us a good understanding of the noise behavior of this laser.

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